

## **Quarterly Reliability Monitoring Results**

## Quarters: Q1/2021 to Q4/2021

Based on structural similarity

Supplier Nexperia B.V. Name of Laboratory		User Part Number PBHV9050T Part Description													
											Nexperia DHAM	Small Signal E	Bipolar Transist	or	
									Assembly reliability labs		SMD package				
Based on AEC-Q101 Test		Test Conditions	Duration	# Lots	# Quantity	# Rejects									
	TEST														
	Pre- and Post-Stress														
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below									
		JESD22-A113 Bake Tamb = 125 °C	24 hours												
	PC	Soak Tamb = 85 °C, RH = 85%	168 hours												
# A1	Preconditioning	Reflow soldering	3 cycles	849	61170	0									
		MIL-STD-750-1													
	HTRB	M1039 Method A													
		Tj = Tjmax, Vr = 100% of max. datasheet													
# B1	Bias	reverse voltage	1000 hours	202	16160	0									
	тс	JESD22-A104													
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	171	13680	0									
# AT	. ,	IESD22-A102	1000 cycles	1/1	13000	0									
	AC	Tamb = 121 °C, RH = 100 %													
# A3 alt	Autoclave	Pressure = 205 kPa (29.7 psia)	96 hours	173	13840	0									
	H3TRB	JESD22-A101													
	High Humidity High	Tamb = 85 °C, RH = 85%, VR = 80 % of													
# A2 alt	Temperature Reverse Bias		1000 hours	173	13840	0									
	701	MIL-STD-750 Method 1037													
# A5	IOL Intermittent Operating Life	ton = toff, devices powered to insure $\Delta Tj$ =	1000 have-	107	15760	0									
# A5	Intermittent Operating Life	100 C for 15000 Cycles	1000 hours	197	15760	0									
	RSH	JESD22-A111													
# C8	Resistance to Solder Heat	260 °C ± 5 °C	10 s	135	4050	0									
	SD					-									
# C10	Solderability	J-STD-002		342	3420	0									

<sup>[1]</sup> The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1)
Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia	Small Signal Bipolar				
DHAM	Transistor	16160	0	0.26	3.81E+09

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